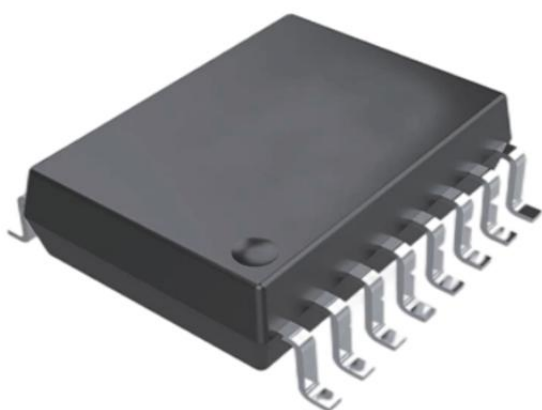




晶体管光耦 Photo Transistor

ELQ3H7

Product Data Sheet

AOTE DCC
RELEASE

台湾奥特半导体科技有限公司

TAIWAN AOTE SEMICONDUCTOR TECHNOLOGY CO.,LTD

www.aotesemi.com

概述 Description

ELQ3H7是一款由发光二极管和光电晶体管组成的光电耦合器。十六引脚封装（SSOP16）。

The ELQ3H7 is a photoelectric coupler composed of light-emitting diode and phototransistor. It is packaged in a 16-pin package at SSOP16.

特性 Features

- 电流转换比(CTR)范围: 50% ~600% ($I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$, $T_a = 25^\circ\text{C}$)
Current transfer ratio: 50% ~600% ($I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$, $T_a = 25^\circ\text{C}$)
- 输入-输出隔离电压 ($V_{ISO} = 3750\text{ Vrms}$)
High isolation voltage between input and output ($V_{ISO} = 3750\text{ Vrms}$)
- 集电极-发射极击穿电压 $BV_{CEO} \geq 80\text{V}$
Collector - emitter breakdown voltage $BV_{CEO} \geq 80\text{V}$
- 工作温度: $-55^\circ\text{C} \sim +110^\circ\text{C}$
Operating Temperature: $-55^\circ\text{C} \sim +110^\circ\text{C}$
- 符合加强绝缘标准
Meet reinforced insulation standards
- 符合安规标准: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5), CQC11-471543-2022
Meet safety standard approval: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5), CQC11-471543-2022

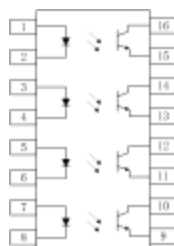
应用 Applications

- DC-DC 转换器
DC-DC converter
- 通讯设备
Communications equipment
- 可编程控制器
Programmable controller
- 信号传输
Signal transmission

封装和原理图 Package and Schematic Diagram



SSOP16



Pin Configuration

- 1. Anode
- 2. Cathode
- 15. Emitter
- 16. Collector

印字信息 Marking Information

- 印字中 “” 为奥特品牌 LOGO
“” denotes LOGO
- 印字中 “Y” 代表年份； A(2018),B(2019),C(2020)
“Y” denotes YEAR： A(2018), B(2019), C(2020)
- 印字中 “WW” 代表周号
“WW” denotes Week’ s number
- 印字中 “E” 代表内部代码
“E” denotes Internal code
- 印字中的 “H” 代表无卤
“H” denotes Halogen-free



绝缘和安规信息 Insulation and Safety related specifications

项目 Item	符号 Symbol	数值 Value	单位 Unit	备注 Remark
爬电距离 Creepage Distance	L	>5.0	mm	从输入端到输出端，沿本体最短距离路径 Measured from input terminals to output terminals, shortest distance path along body
电气间隙 Clearance Distance	L	>5.0	mm	从输入端到输出端，通过空气的最短距离 Measured from input terminals to output terminals, shortest distance through air
绝缘距离 Insulation Thickness	DTI	>0.4	mm	发射器和探测器之间的绝缘厚度 Insulation thickness between emitter and detector
峰值隔离电压 Peak Isolation Voltage	V_{IORM}	600	V_{peak}	DIN/EN/IEC EN60747-5-5
瞬态隔离电压 Transient isolation voltage	V_{IOTM}	5000	V_{peak}	DIN/EN/IEC EN60747-5-5
隔离电压 Isolation Voltage	V_{iso}	> 3750	V_{rms}	For 1 min

极限参数 Absolute Maximum Ratings ($T_a = 25^{\circ}\text{C}$)

参数 Parameter		符号 Symbol	额定值 Rating	单位 Unit
发射端 Input	正向电流 Forward Current	I_F	50	mA
	反向电压 Reverse Voltage	V_R	6	V
	正向峰值电流(1us, pulse) Peak forward current (1us, pulse)	I_{FP}	1000	mA
	功耗 Power Dissipation	P_D	70	mW
接收端 output	集电极功耗 Collector Power Dissipation	P_C	150	mW
	集电极电流 Collector Current	I_C	50	mA
	集电极-发射极电压 Collector-Emitter Voltage	V_{CEO}	80	V
	发射极-集电极电压 Emitter-Collector Voltage	V_{ECO}	7	V
总功耗 Total Power Dissipation		P_{tot}	200	mW
隔离电压 Isolation Voltage		V_{iso}	3750	V_{rms}
工作温度 Operating Temperature		T_{opr}	-55 ~ +110	$^{\circ}\text{C}$
存储温度 Storage Temperature		T_{stg}	-55 ~ +125	$^{\circ}\text{C}$
焊接温度 Soldering Temperature		T_{sol}	260	$^{\circ}\text{C}$

产品特性参数 Electro-optical Characteristics (Ta = 25℃)

参数 Parameter		符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit
发射端 Input	正向电压 Forward Voltage	V_F	$I_F = 20\text{mA}$	-	1.2	1.4	V
	反向电压 Reverse Current	I_R	$V_R = 4\text{V}$	-	-	10	μA
	输入电容 Terminal Capacitance	C_t	$V=0, f=1\text{kHz}$	-	30	250	pF
接收端 Output	集电极暗电流 Collector Dark Current	I_{CEO}	$V_{CE} = 20\text{V}$	-	-	100	nA
	集电极-发射极击穿电压 Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_C = 0.1\text{mA}, I_F = 0\text{mA}$	80	-	-	V
传输特性 Transfer Characteristics	发射极-集电极电压 Emitter-Collector Voltage	V_{ECO}	$I_E = 0.01\text{mA}, I_F = 0\text{mA}$	7	-	-	V
	电流传输比 Current Transfer Ratio	CTR*	$I_F = 5\text{mA}, V_{CE} = 5\text{V}$	50	-	600	%
	集电极-发射极饱和压降 Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_F = 10\text{mA}, I_C = 1\text{mA}$	-	0.1	0.2	V
	隔离电阻 Isolation Resistance	R_{ISO}	DC500V, 40 ~ 60% R.H.	5×10^{10}	1×10^{11}	-	Ω
	隔离电容 Isolation capacitance	C_{ISO}	$V=0, f=1\text{MHz}$	-	0.3	1.0	pF
	上升时间 Rise Time	T_r	$V_{CE} = 2\text{V}, I_C = 2\text{mA}, R_L = 100\Omega$	-	5	18	μs
	下降时间 Fall Time	T_f	$V_{CE} = 2\text{V}, I_C = 2\text{mA}, R_L = 100\Omega$	-	3	18	μs

注*：电流传输比 = $I_C / I_F \times 100\%$ 。

Note*：CTR = $I_C / I_F \times 100\%$ 。

典型光电特性曲线 Typical Electro-Optical Characteristics Curves

Fig.1 Relative Current Transfer Ratio vs. Forward Current

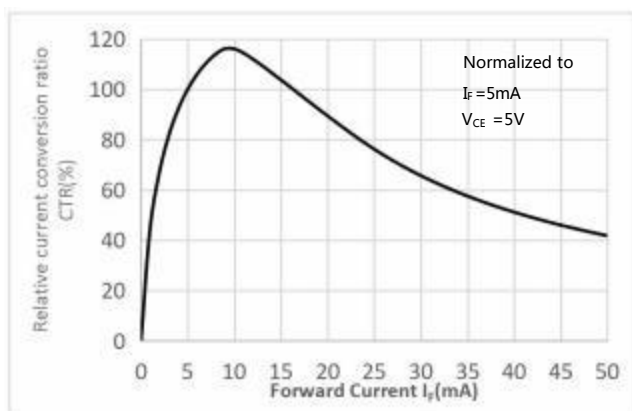


Fig.2 Forward Current vs. Forward Voltage

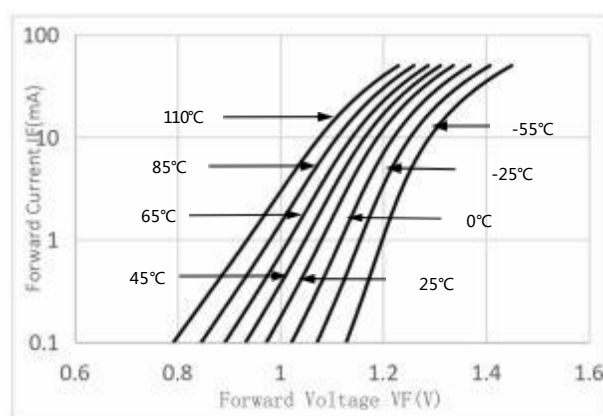


Fig.3 Collector Current vs. Collector-emitter Voltage

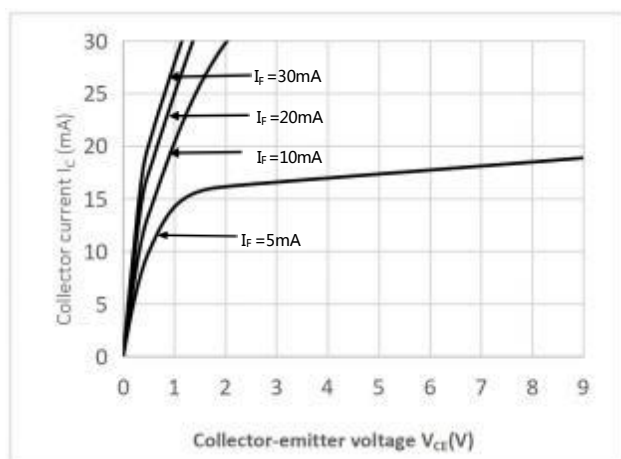


Fig.4 Relative Current Transfer Ratio vs. Ambient Temperature

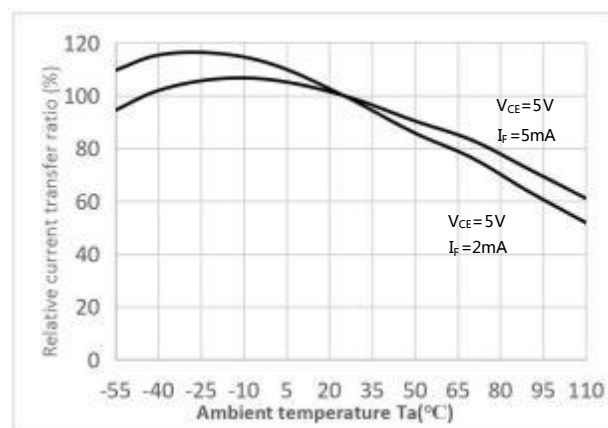


Fig.5 Collector-emitter Saturation Voltage vs. Ambient Temperature

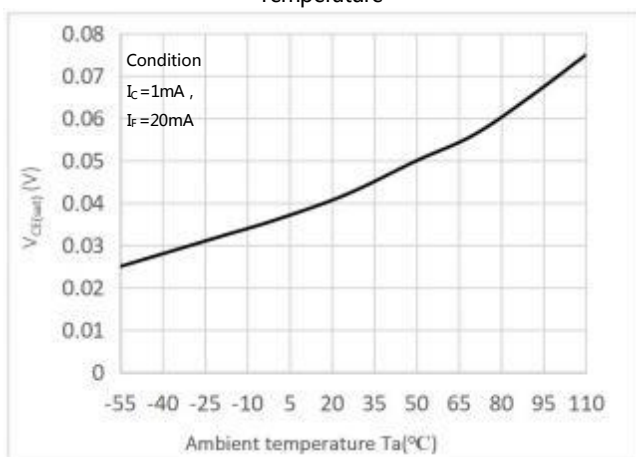


Fig.6 Collector Dark Current vs Ambient Temperature

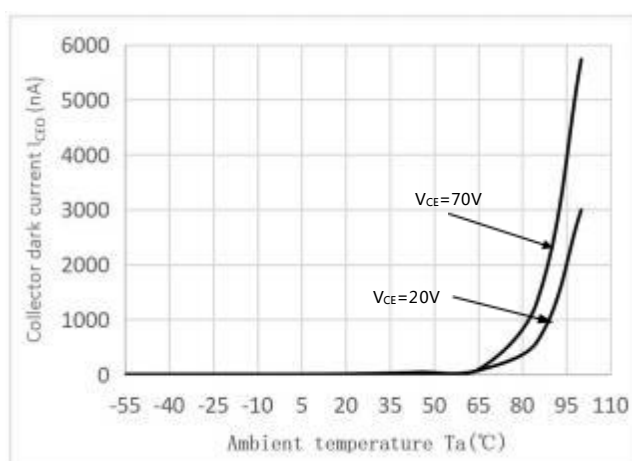


Fig.7 Response Time vs. Load Resistance

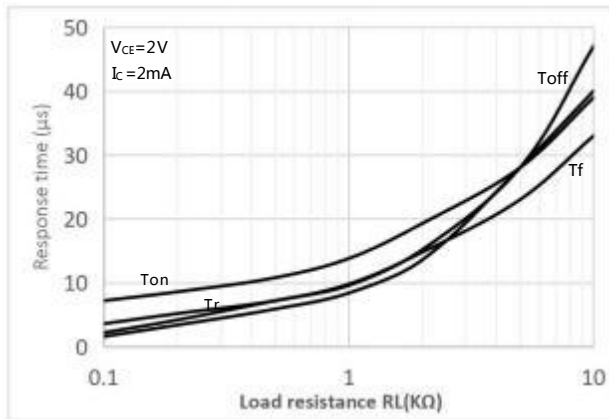


Fig.8 Frequency Response

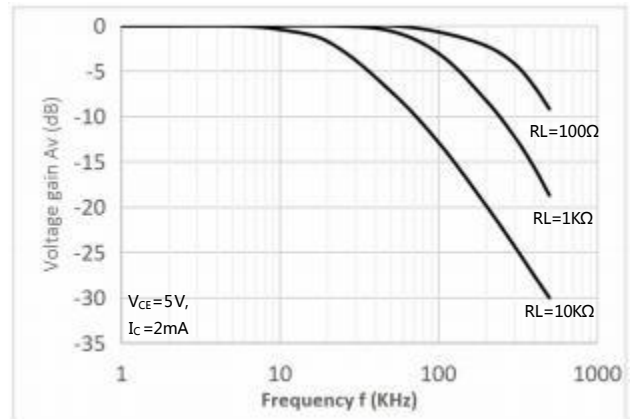


Fig.9 Collector-emitter Saturation Voltage vs Forward Current

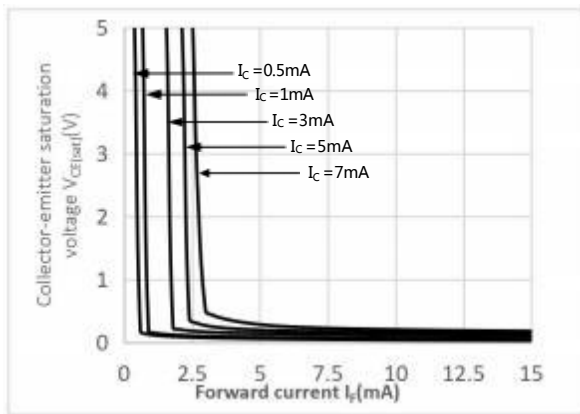
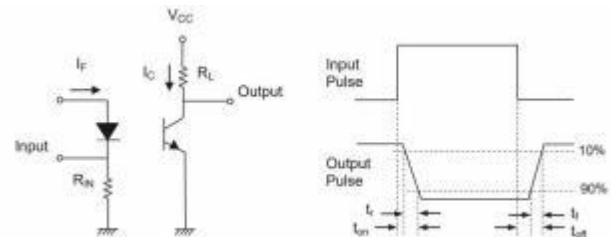
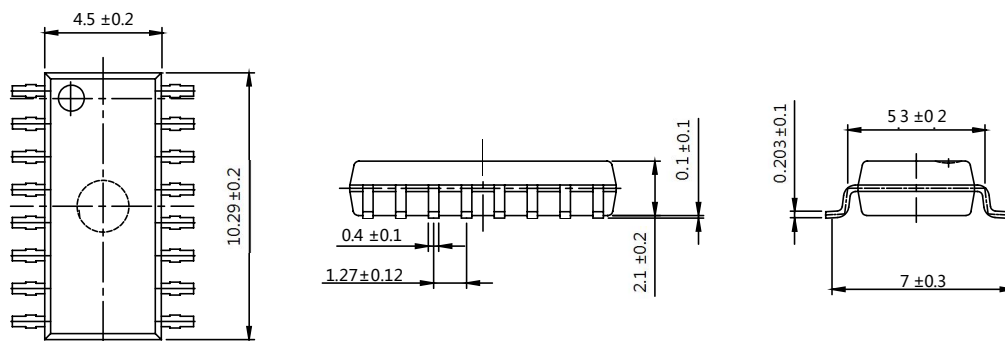


Fig.10 Switching Time Test Circuit & Waveforms



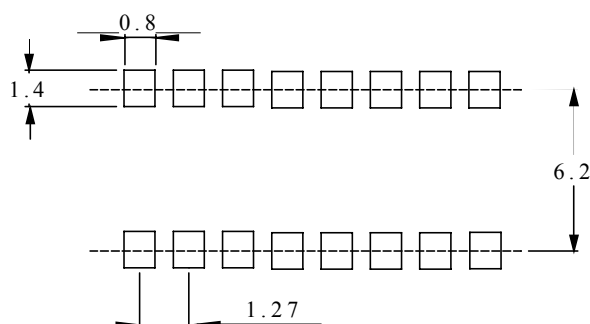
外形尺寸 Outline Dimensions

SSOP16



单位 Unit: mm

建议焊盘布局 Recommended Pad Layout

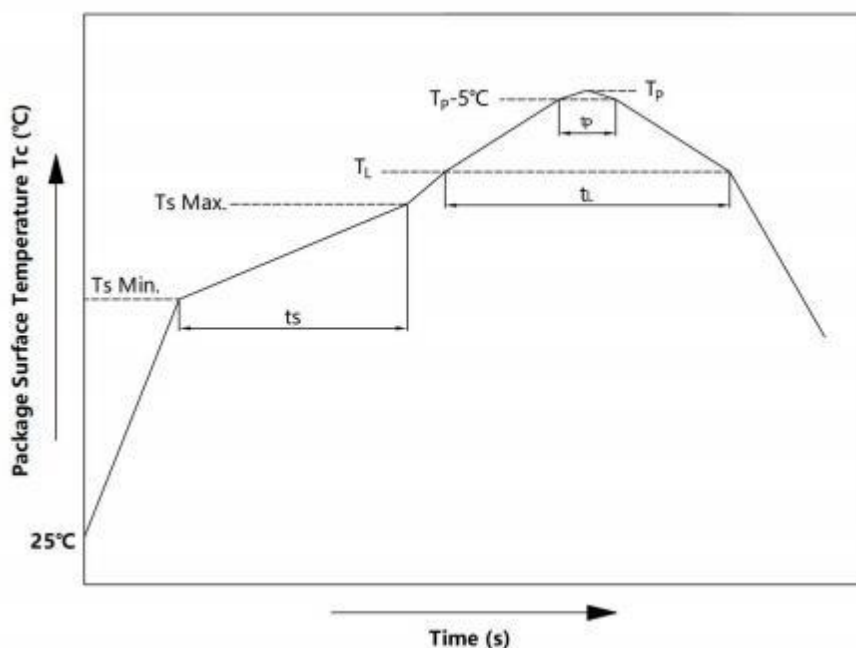


单位 Unit: mm

注：上图为产品正视图。

Note: The picture above is the front view of the product.

回流焊温度曲线图 Solder Reflow Profile



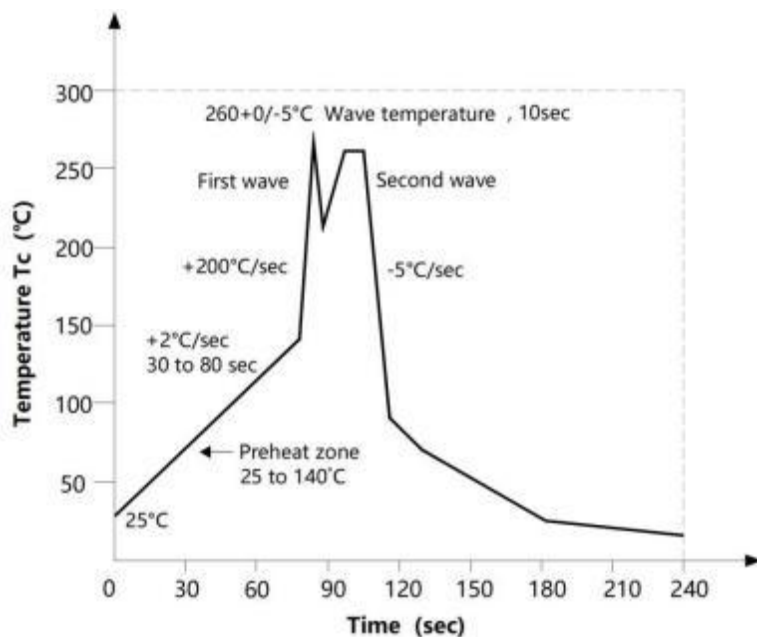
项目 Item	符号 Symbol	最小值 Min.	最大值 Max.	单位 Unit
预热温度 Preheat Temperature	T_s	150	200	°C
预热时间 Preheat Time	t_s	60	120	s
升温速率 Ramp-Up Rate (T_L to T_P)	-	-	3	°C/s
液相线温度 Liquidus Temperature	T_L	217		°C
时间高于 T_L Time Above T_L	t_L	60	150	s
峰值温度 Peak Temperature	T_P	-	260	°C
T_c 在 $(T_P - 5)$ 和 T_P 之间的时间 Time During Which T_c Is Between $(T_P - 5)$ and T_P	t_p	-	30	s
降温速率 Ramp-down Rate (T_P to T_L)	-	-	6	°C/s

注 Note :

建议在所示的温度和时间条件下进行回流焊，最多不能超过三次；

Reflow soldering is recommended at the temperatures and times shown, no more than three times;

波峰焊温度曲线图 Wave Soldering Profile



手工烙铁焊接 Soldering with hand soldering iron

A. 手工烙铁焊仅用于产品返修或样品测试；

Hand soldering iron is only used for product rework or sample testing;

B. 手工烙铁焊要求：温度 $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$ ，时间 $\leq 3\text{s}$ 。

Hand soldering iron requirements：Temperature： $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$, within 3s.

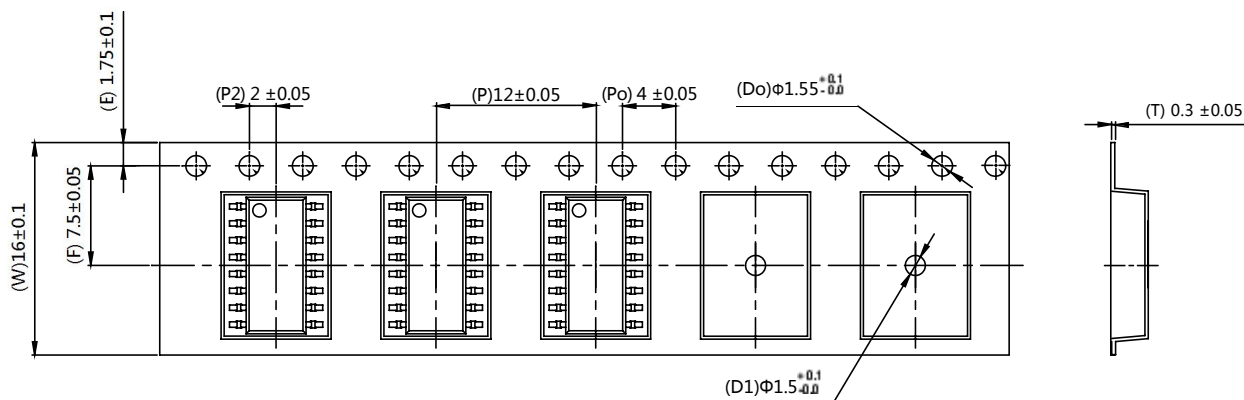
包装 Packing

■ 汇总表 Summary table

封装形式	包装方式	盘数量	盒数量	箱数量	静电袋规格	盒规格	箱(双瓦楞)规格	备注
SSOP16	卷盘 ($\phi 330\text{mm}$ 蓝盘)	2000 只/盘	2 盘/盒	10 盒/箱	450*390*0.1mm	34*6*34cm	38*36*36.5cm	首端各空 50 个空格 , 末端空 100
Package Type	Packing Form	Quantity per Reel	Quantity per Box	Quantity per Carton	Antistatic Bag Specification	Box Specification	Carton Specification	Note
SSOP16	Reel ($\phi 330\text{mm}$ Blue)	2000 pcs /reel	2 reels /box	10 boxes /ctn	450*390*0.1mm	34*6*34cm	38*36*36.5cm	Leave 50 Spaces at the beginning and 100 Spaces at the end

■ 编带包装 Tape & Reel

- 1) 每卷数量：2000 只。
Qty/reel：2000 pcs.
- 2) 每箱数量：40000 只。
Qty/ctn：40000 pcs.
- 3) 内包装：每盒 2 盘。
Inner packing：2 reels/box.
- 4) 示意图 Schematic：



单位 Unit：mm

注意 Attention

- 奥特持续不断改进质量、可靠性、功能或设计，保留此文件更改的权利恕不另行通知。
AOTE continuously improve quality, reliability, function and design. We reserve the right to change this document without prior notice.
- 请遵守产品规格书使用，奥特不对使用时不符合产品规格书条件而导致的质量问题负责。
Please use in accordance with the product specification. AOTE is not responsible for the quality problems caused by non-compliance with the product specifications.
- 对于需要高可靠性或安全性的设备/装置需求，请联系我们的销售人员。
For equipment/devices requiring high reliability or safety, please contact our sales representatives.
- 当需要用于任何“特定”应用时，请咨询我们的销售人员。
When requiring a device for any “specific” application, please contact our sales in advice.
- 如对文件中表述的内容有疑问，欢迎联系我们。
If you have any questions about the contents of the document, please contact us.